



PATENT
3672-0110P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant:	Lucimara S. ROMAN et al.	Conf.:	9297
Appl. No.:	09/720,329	Group:	2818
Filed:	February 6, 2001	Examiner:	D. VU
For:	A METHOD IN FABRICATION OF ORGANIC THIN-FILM SEMICONDUCTING DEVICES		

LARGE ENTITY TRANSMITTAL FORM

Assistant Commissioner for Patents
Washington, DC 20231

March 17th 2003

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Sir:

Transmitted herewith is an amendment in the above-identified application.

- ☐ The enclosed document is being transmitted via the Certificate of Mailing provisions of 37 C.F.R. § 1.8.
- ☐ The enclosed document is being transmitted via facsimile.

The fee has been calculated as shown below:

	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR		PRESENT EXTRA	RATE	ADDITIONAL FEE
TOTAL	18	-	20	=	0	\$18	\$0.00
INDEPENDENT	2	-	3	=	0	\$84	\$0.00
<input type="checkbox"/> FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$280	\$0.00
						TOTAL	\$0.00

Appl. No. 09/720,329

- ☐ Petition for () month(s) extension of time pursuant to 37 C.F.R. §§ 1.17 and 1.136(a). \$0.00 for the extension of time.
- ☒ No fee is required.
- ☐ Check(s) in the amount of \$0.00 is(are) enclosed.
- ☐ Please charge Deposit Account No. 02-2448 in the amount of \$0.00. This form is submitted in triplicate.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By ma armstrong
MaryAnne Armstrong, PhD., #40,069

MKM/MAA/csm
3672-0110P

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Attachment(s)

(Rev. 10/15/02)



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APPLICANTS: Lucimara S. ROMAN et al. CONF.: 9297
APPLN. NO.: 09/720,329 GROUP: 2818
FILED: February 6, 2001 EXAMINER: VU, David
FOR: A METHOD IN FABRICATION OF ORGANIC THIN-FILM
SEMICONDUCTING SERVICES

AMENDMENT UNDER 37 C.F.R. § 1.111

Assistant Commissioner for Patents
Washington, D.C. 20231

March 17, 2003

Sir:

Responsive to the Examiner's Office Action dated December 19, 2002, the following amendments and Remarks are respectfully submitted in connection with the above-identified application.

IN THE CLAIMS

Please replace claim 1 with the following amended claim.

1. (Twice Amended) A method in the fabrication of an electrode structure for an organic thin-film semiconducting device, wherein the semiconducting device is a rectifying diode with a high rectification ratio of an organic thin-film transistor or a hybrid organic/inorganic thin-film transistor comprises

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